DG9431E



Vishay Siliconix

1 pC Charge Injection, 100 pA Maximum Leakage, +5 V / +3 V, **SPDT Analog Switch**

DESCRIPTION

The DG9431E is a monolithic CMOS switch designed for precision signal switching. The 17 Ω low voltage part exhibits low charge injection over the full signal range, low leakage, low parasitic capacitance, and fast switching.

The DG9431E can switch both analog and digital signals. Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make switching is guaranteed.

The DG9431E offers 1 nW typical power consumption and 8 kV ESD (HBM), 1 kV ESD (CDM) tolerance. It is ideal for use in low voltage instruments and healthcare devices, fitting the circuits of low voltage ADC and DAC, sample and hold, analog front end gain control, and signal path switching. The DG9431E is available in 6-lead TSOP and 8-lead SOIC packages.

APPLICATIONS

- Automatic test equipment
- · Process control and automation
- · Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- · Sample-and-hold systems
- Relay replacements
- Battery powered systems

FEATURES

25 °C

- 1 pC charge injection
- Guaranteed 100 pA max. switch on leakage at RoHS
- 3.8 pF switch off and 7.8 pF switch on capacitances
- +2.7 V to +5 V single supply operation
- Low on-resistance R_{DS(on)}: 17 Ω (typ.) at 5 V
- t_{ON}: 32 ns, t_{OFF}: 10 ns switching time
- Typical power consumption: 1 nW
- · Over voltage tolerance on logic control IN pin
- TTL / CMOS compatible
- ESD (HBM): > 8000 V, ESD (CDM): >1000 V
- Latch-up current: > 300 mA (JESD78)
- Available in TSOP-6 and SOIC-8

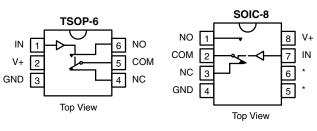
Note

This datasheet provides information about parts that are RoHS-compliant and / or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details.

BENEFITS

- Low charge injection and leakage
- Low parasitic capacitance
- · Fast switching speed
- High ESD tolerance

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



*Not Connected

TRUTH TABLE						
LOGIC	NO					
0	ON	OFF				
1	OFF	ON				

Note

Logic "0" \leq 0.8 V Logic "1" ≥ 2.4 V

ORDERING INFORMATION							
TEMP. RANGE	TEMP. RANGE CONFIGURATION PART NUMBER PACKAGE MINIUM ORDER / PACKAGING QUAI						
	°C to +85 °C DG9431E	6-pin TSOP	DG9431EDV-T1-GE3	Tape and reel 3000 units			
-40 °C to +85 °C		8-pin SOIC	DG9431EDY-T1-GE3	Tape and reel 2500 units			
			DG9431EDY-GE3	Tube 500 units			

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	LIMIT	UNIT				
Reference V+ to GND	-0.3 to +6	v				
IN, COM, NC, NO ^a		-0.3 to (V+ + 0.3)	v			
Continuous current (any terminal)		± 20	mA			
Peak current (pulsed at 1 ms, 10 % duty cycle)	± 40	- IIIA				
ESD (HBM) (MIL-STD-883, method 3015)	> 8000	v				
ESD (CDM) (ANSI / ESDA / JEDEC [®] JS-002)	> 1000	v				
Latch up current, per JESD78	300	mA				
Storage temperature (D suffix)	-65 to +125	°C				
Power dissipation (packages) ^b	8-pin narrow body SOIC ^c	400	mW			
i ower dissipation (packages) -	6-pin TSOP ^d	570	11100			

Notes

a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 6.5 mW/°C above 75 °C.

d. Derate 7 mW/°C above 70 °C.

SPECIFICATIONS (V+ =	= 3 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^a	D SUFFIX -40 °C TO +85 °C			UNIT			
		V+ = 3 V, \pm 10 %, V _{IN} = 0.8 V or 2.4 V $^{\rm e}$		MIN. °	TYP. ^b	MAX. °	•••••			
Analog Switch										
Analog signal range ^d	V _{ANALOG}		Full	0	-	3	V			
Drain-source on-resistance	R _{DS(on)}	V_{NO} or V_{NC} = 1.5 V, V+ = 2.7 V I_{COM} = 5 mA	Room	-	35	50				
R _{DS(on)} match ^d	$\Delta R_{DS(on)}$	$\frac{V_{NO} \text{ or } V_{NC} = 1.5 \text{ V}}{V_{NO} \text{ or } V_{NC} = 1.5 \text{ V}}$	Full Room	-	- 0.4	65 2	Ω			
R _{DS(on)} flatness ^f	R _{DS(on)} flatness	V_{NO} or V_{NC} = 1 V and 2 V	Room	-	4	8	55			
	I		Room	-100	5	100	рА			
NO or NC off leakage current ^g	I _{NO/NC(off)}	V_{NO} or V_{NC} = 1 V / 2 V, V_{COM} = 2 V / 1 V	Full	-5000	-	5000				
	1	V_{COM} = 1 V / 2 V, V_{NO} or V_{NC} = 2 V / 1 V	Room	-100	5	100				
COM off leakage current ^g	ICOM(off)		Full	-5000	-	5000				
Channel-on leakage current ^g	I _{COM(on)}	$V_{COM} = V_{NO}$ or $V_{NC} = 1 \text{ V} / 2 \text{ V}$	Room	-200	5	200				
Channel-On leakage current s		$v_{COM} = v_{NO} \text{ or } v_{NC} = 1 \text{ or } 72 \text{ or }$	Full	-10 000	-	10 000				
Digital Control							-			
Input current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-	0.001	-	μA			
Dynamic Characteristics							-			
Turn-on time	t _{on}		Room	-	43	120	ns			
			Full	-	-	200				
Turn-Off Time		V_{NO} or V_{NC} = 1.5 V	Room		16	50				
Tum-On Time	UFF	t _{OFF}	Full	-	-	120				
Break-before-make time	t _d		Room	3	26	-				
Charge injection	Q _{INJ}	$C_L = 1 \text{ nF}, V_{gen} = 0 \text{ V}, \text{ R}_{gen} = 0 \Omega$	Room	-	-0.28	-	рС			
Off-isolation	O _{IRR}	$R_1 = 50 \Omega, C_1 = 5 pF, f = 1 MHz$	Room	-	-80	-	dB			
Crosstalk	X _{TALK}	$R_{L} = 50 \Omega_{2}, C_{L} = 5 \text{ pr}, T = T \text{ Minz}$	Room	-	-108	-	uБ			
Source off capacitance	C _{S(off)}	f = 1 MHz	Room	-	4	-	рE			
Channel-on capacitance	C _{D(on)}	T = 1 MHZ Room		-	8	-	pF			
Power Supply										
Power supply range	V+			2.7	-	5.5	V			
Power supply current	l+	V+ = 3.3 V, V _{IN} = 0 V or 3.3 V - 0.0003 1			μA					

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DG9431E

Vishay Siliconix

SPECIFICATIONS (V+ = 5 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. ^a	D SUFFIX -40 °C to +85 °C			UNIT		
		V+ = 5 V, \pm 10 %, V _{IN} = 0.8 V or 2.4 V $^{\rm e}$		MIN. ^c	TYP. ^b	MAX. ^c			
Analog Switch									
Analog signal range ^d	V _{ANALOG}		Full	0	-	5	V		
Drain-source on-resistance	R _{DS(on)}	V_{NO} or V_{NC} = 3.5 V, V+ = 4.5 V	Room	-	17	25	-		
	US(on)	$I_{COM} = 5 \text{ mA}$	Full	-	-	35			
R _{DS(on)} match ^d	$\Delta R_{DS(on)}$	V_{NO} or V_{NC} = 1.5 V	Room	-	0.4	2	Ω		
R _{DS(on)} flatness ^f	R _{DS(on)} flatness	$V_{NO} \text{ or } V_{NC}$ = 1 V, 2 V, and 3 V	Room	-	3.5	6			
NO or NC off leakage current	hua nua con	V_{NO} or V_{NC} = 1 V / 4 V, V_{COM} = 4 V / 1 V	Room	-100	10	100	рА		
NO OF NO OF leakage current	I _{NO/NC(off)}		Full	-5000	-	5000			
COM off leakage current	leave a	$V_{COM} = 1 \text{ V} / 4 \text{ V}, V_{NO} \text{ or } V_{NC} = 4 \text{ V} / 1 \text{ V}$	Room	-100	10	100			
Com on leakage current	I _{COM(off)}		Full	-5000	-	5000			
Channel-on leakage current	I _{COM(on)}	$V_{COM} = V_{NO} \text{ or } V_{NC} = 1 \text{ V} / 4 \text{ V}$	Room	-200	-	200			
Channel-On leakage current			Full	-10 000	-	10 000			
Digital Control							-		
Input current	$I_{\rm INL}$ or $I_{\rm INH}$		Full	-	0.001	-	μA		
Dynamic Characteristics									
Turn-on time	t _{ON}		Room	-	32	75	ns		
	LON		Full	-	-	150			
Turn-off time	torr	V_{NO} or $V_{NC} = 3 V$	Room	-	10	50			
	OFF		Full	-	-	100			
Break-before-make time	t _d		Room	3	22	-			
Charge injection	Q _{INJ}	C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room	-	-0.78	-	рС		
Off-isolation	O _{IRR}	R _I = 50 Ω, C _I = 5 pF, f = 1 MHz	Room	-	-80	-	dB		
Crosstalk	X _{TALK}	$M_{\rm L} = 50.22; 0{\rm L} = 5.0{\rm H}^2; 1 = 1.0{\rm H}^2$	Room	-	-108	-	ub		
NC and NO capacitance	C _(off)	f = 1 MHz	Room	-	3.8	-	pF		
Channel-on capacitance	C _{D(on)}	I = I MHZ		-	7.8	-	γ		
Power Supply									
Power supply range	V+			2.7	-	5.5	V		
Power supply current	l+	V+ = 5.5 V, V _{IN} = 0 V or 5.5 V		-	0.0004	1	μA		

Notes

a. Room = 25 °C, Full = as determined by the operating suffix.

b. Typical values are for design aid only, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.

d. Guarantee by design, nor subjected to production test.

e. V_{IN} = input voltage to perform proper function.

f. Difference of min and max values.

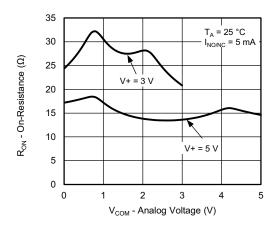
g. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

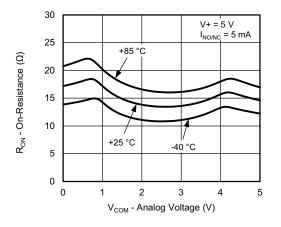
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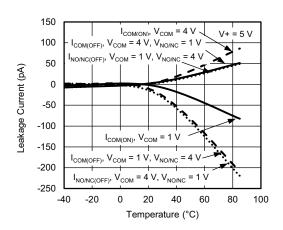
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



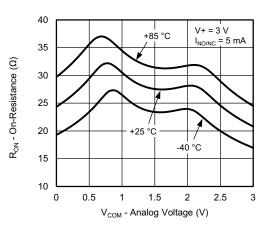
On-Resistance vs. Analog Voltage



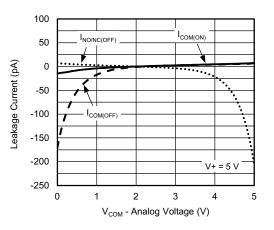
On-Resistance vs. Analog Voltage



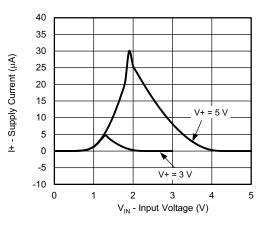
Leakage Current vs. Temperature



On-Resistance vs. Analog Voltage



Leakage Current vs. Analog Voltage



Supply Current vs. Input Voltage

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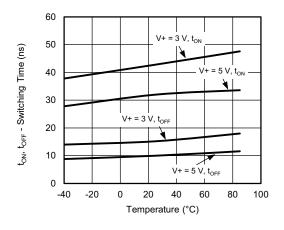
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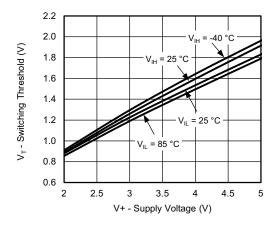
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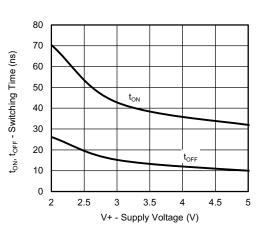
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



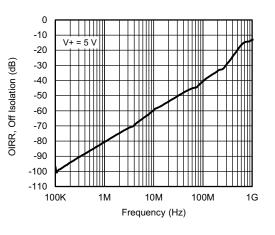
Switching Time vs. Temperature



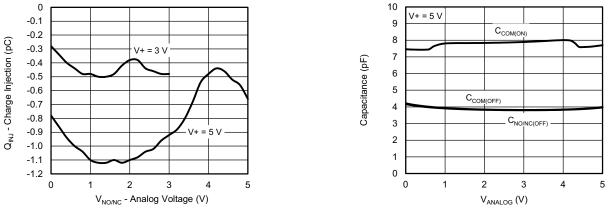
Switching Threshold vs. Supply Voltage



Switching Time vs. Supply Voltage



OIRR, Off Isolation vs. Frequency



Charge Injection vs. Analog Voltage

Capacitance

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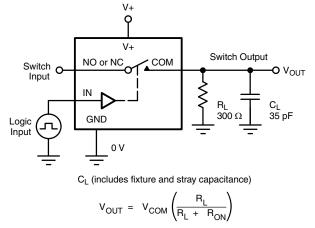
DG9431E

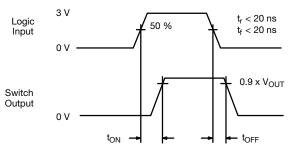
t_r < 5 ns

t_f < 5 ns

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TEST CIRCUITS





Logic "1" = switch on Logic input waveforms inverted for switches that have the opposite logic sense.



Logic

Input

 $V_{NC} = V_{NO}$

Switch

Output

3 V

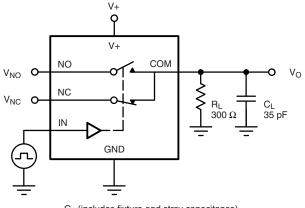
0 V

 V_{O}

0 V

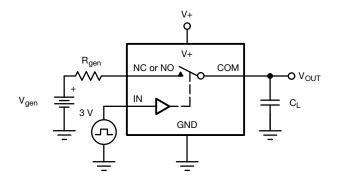
90 %

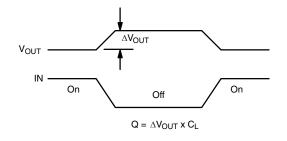
tD



CL (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

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TEST CIRCUITS

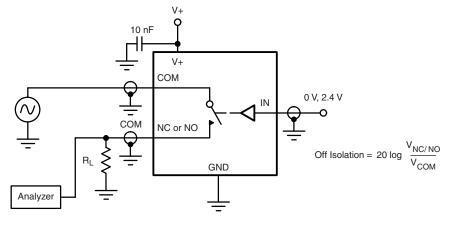


Figure 4. Off-Isolation

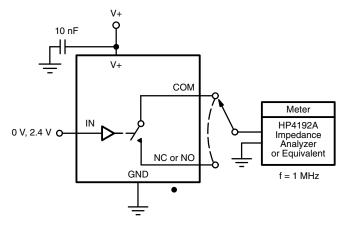


Figure 5. Channel Off/On Capacitance

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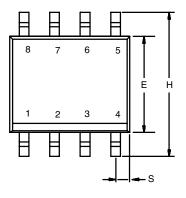


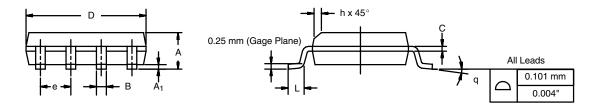
Package Information

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SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012





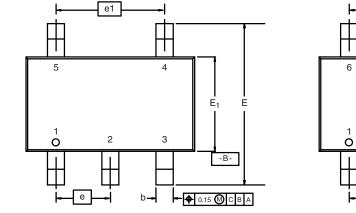
	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						



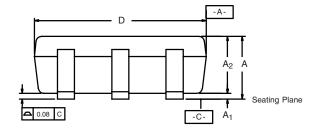
Package Information

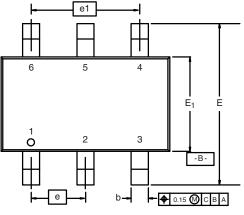
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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C

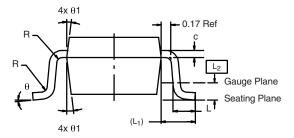








6-LEAD TSOP



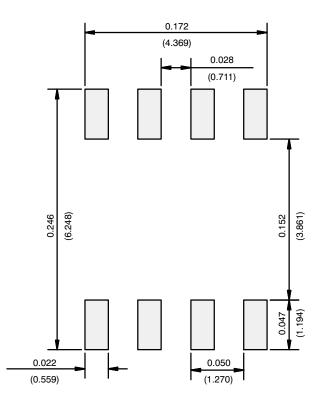
	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	16 0.120 (
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC		0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.071 0.075		
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref			0.024 Ref		
L ₂		0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom 7° Nom						
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

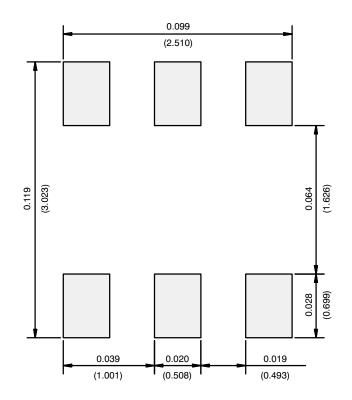
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Application Note 826

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RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads Dimensions in Inches/(mm)

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